

2000

1000000

1230

53815

1000000



Part Number: **UMCxN-p, UMGxN-p** p = package designator x=4,5 Weight (mg): 6.1396 See Data Sheet

Carbon black

Tin

Average mass Percent ppm CAS (if Material Element Materials Mass (mg) homogeneous of whole Homogeneous ppm overall applicable) Group Materal(%) (%) Material Silicon w/Metal Doped Silicon* 7440-21-3 Chip 100.00% 3.04 0.1866 1000000 30393 7439-89-6 57 65% Fe 576500 165327 7440-02-0 Ni 41 00% 410000 117579 Mn 7439-96-5 0.60% 6000 172 Leadframe Alloy 42 28.68 1.7607 Cr(not Cr 6+) 7440-47-3 0.10% 1000 287 7440-48-4 0.50% 5000 1434 Со 7440-21-3 0.15% 430 Si 1500 Leadframe Plating 0.0611 Silver Silver 7440-22-4 100.00% 1.00 1000000 9952 Gold Wire 0.41 Bond Wire Gold 7440-57-5 100.00% 0.0252 1000000 410 Silica 60676-86-0 87.30% 873000 536859 Basic Duromer: Epoxy resin (Compound of a 5.00% 50000 30748 polymeric network) 3.7756 Encapsulation CEL-1702HF-9 Basic Duromer:Phenolic resin (Compound of 61.50 5.00% polymeric network) 50000 30748 system 2.50% 15374 Misc. 25000

Tolerance ±10%

Matte Tin

Lead Plating Finish

This data is based on information provided by our suppliers. We believe it to be correct but do not routinely validate it by measurement. It is for guidance only and Diodes Inc. does not guarantee its absolute accuracy or completeness

1333-86-4

7440-31-5

This product or product family does not contain any of the following substances except as CURRENTLY exempted by ELV II and RoHS and reported above:

Asbestos

Antimony Compounds

Azo compounds

Cadmium and cadmium compounds
Certain Shortchain Chlorinated Paraffins

Chlorinated organic compounds

Dimethyl fumarate

Halogens

Hexavalent chromium compounds

Lead and lead compounds

Mercury and mercury compounds

REACH SVHCs and other Substances of Concern:

Anthracene

4,4'- Diaminodiphenylmethane

Dibutyl phthalate Cyclododecane Cobalt dichloride Diarsenic pentaoxide

Diarsenic trioxide Sodium dichromate, dihydrate

Beryllium, Beryllium Alloys and Compounds

Hydrazine Tetrachloroethylene Toluene

Toluene Diisocyanate

Organic tin compounds

Ozone Depleting Substances - Class I (CFCs, HBFCs, etc.)

0.20%

100.00%

5.38

100.00

0.3304

6.1396

Ozone Depleting Substances - Class II (HCFCs)

Perfluorooctane Sulphonate (PFOS) or related compounds

Polybrominated biphenyls (PBB) and Polybrominated diphenyl ethers (PBDE) including DecaBD

Polychlorinated Biphenyls (PCBs)

Polychlorinated Naphthalenes (> 3 chlorine atoms)

Radioactive Substances

Red Phosphorous

Tributyl Tin (TBT) and Triphenyl Tin (TPT)

Tributyl Tin Oxide (TBTO)

5-tert-butyl-2,4,6-trinitro-m-xylene (musk xylene)

Bis (2-ethyl(hexyl)phthalate) (DEHP) Hexabromocyclododecane (HBCDD)

Alkanes, C10-13, chloro (Short Chain Chlorinated Paraffins)

Bis(tributyltin)oxide Lead hydrogen arsenate Triethyl arsenate Benzyl butyl phthalate

Methylene Chloride Trichloroethene Methyl Ethyl Ketone

Xylenes

^{*} The Silicon Chip is doped at atomic levels with trace amounts of elements that may include Phosphorus, Boron, Arsenic, and other elements. Metalization may include Titanium, Nickel, Aluminum, Silver or Gold These substances are not reported where their concentration is less than the minimum reportable level per the guidelines specified in the Tables of EIA JIG-101, <u>Material Composition Declaration for Electronic Products</u>.